

國立彰化師範大學 102 學年度碩士班招生考試試題

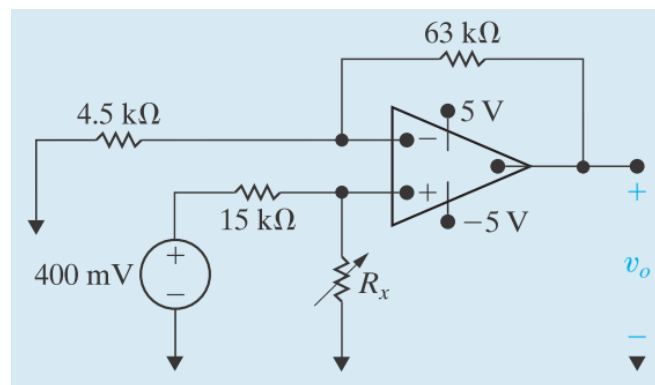
系所：機電工程學系、電子工程學系、資訊工程學系積體電路設計碩士班、車輛科技研究所(選考丁)

科目：電子學

☆☆請在答案紙上作答☆☆

共 2 頁，第 1 頁

1. Consider a 4-bit digital word $D = b_3 b_2 b_1 b_0$ used to represent an analog signal v_A that varies between 0 V and + 15 V. Give D corresponding to $v_A = 9$ V and 11 V. (8 %)
2. Explain the following terminologies: (12 %)
 - (a) Ideal operational amplifier
 - (b) Noise margin
 - (c) Early voltage
3. Assume the operational amplifier for following figure is ideal. What is the output voltage v_o if the resistance of R_x is 60 k Ω ? (8 %)



4. For a pn junction with $N_A = 10^{17}/\text{cm}^3$ and $N_D = 10^{16}/\text{cm}^3$, find, at $T = 300$ K, (a) the built-in voltage, V_0 , (b) the width of the depletion region, W_{dep} , and (c) the distance it extends in the p side, x_p , and the n side of the junction, x_n . Use $n_i = 1.5 \times 10^{10}/\text{cm}^3$, $V_T = 25$ mV, and $\epsilon_s = 1.04 \times 10^{-12}$ F/cm at $T = 300$ K. (12 %)
5. For the circuit shown in Fig.1, the transistor has $\beta = 100$ and $V_A = \infty$. (1) Find the dc current I and the dc voltage V_{CB} if $v_s = 0$. (2) Determine the small-signal voltage gain v_o/v_s , and the output resistance R_o . (20%)
6. In the circuit of Fig. 2, the transistor has $W/L = 100$, $\chi = 0.2$, and $\lambda = 0.05 \text{ V}^{-1}$, $V_{OV} = 0.5$ V, and $k'_n = 160 \mu\text{A}/\text{V}^2$. (1) What is the amplifier configuration? (CS, CG, CD). (2) Determine the bias current I and voltage gain v_o/v_i . (10%)

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共 2 頁，第 2 頁

7. An NMOS differential pair is biased by a current source $I = 0.2 \text{ mA}$ having an output resistance $R_{CS} = 200 \text{ k}\Omega$. The amplifier has drain resistances $R_D = 20 \text{ k}\Omega$, using transistors with $k'_n = 200 \mu\text{A/V}$, $W/L = 10$, and neglecting r_o . If the output is taken differentially and there is a 2% mismatch between the drain resistances, find $|A_d|$, $|A_{cm}|$, and CMRR. (15%)
8. A common-source amplifier has $R_{in} = 200 \text{ k}\Omega$, $R_D = 10 \text{ k}\Omega$. The transistor has $g_m = 2 \text{ mA/V}$, $r_o = 100 \text{ k}\Omega$, $C_{gs} = 1.5 \text{ pF}$, and $C_{gd} = 0.5 \text{ pF}$. The amplifier is fed from a voltage source v_s with an internal resistance of $200 \text{ k}\Omega$ and is connected to a $10 \text{ k}\Omega$ load. Find: (a) the overall midband voltage gain $A_M = v_o / v_s$. (b) the upper 3-dB frequency f_H . (15%)

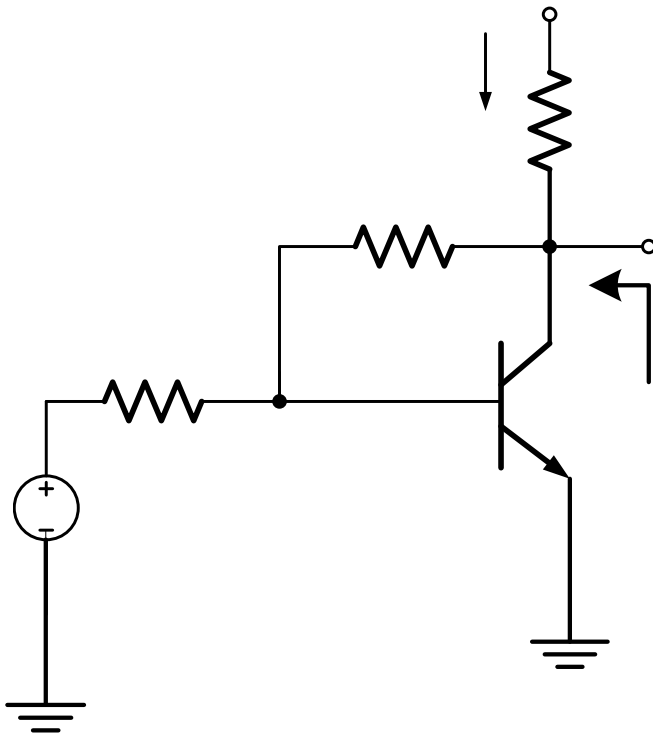


Fig. 1

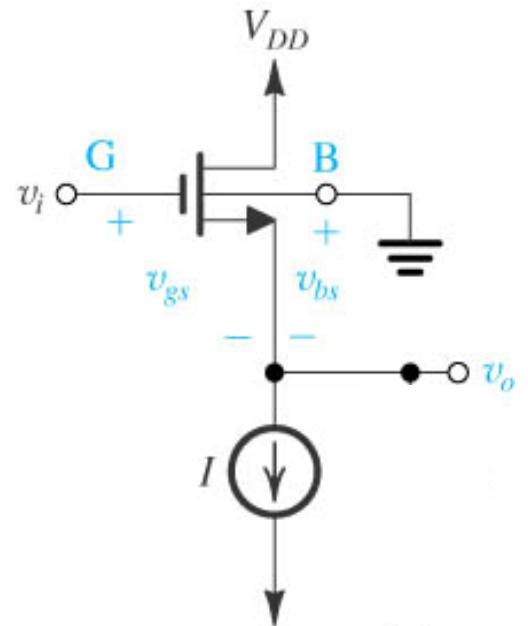


Fig. 2

12 V